CSD18541F5 60-V N-Channel FemtoFET™ MOSFET

1 Features

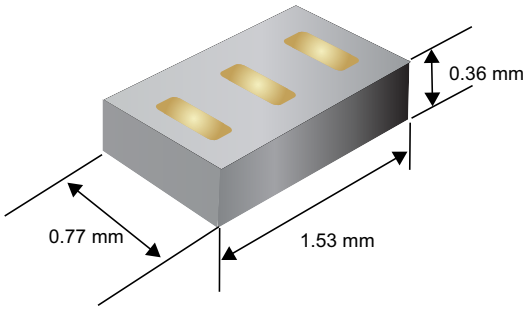
- Low on-resistance
- Ultra-low Q_g and Q_{gd}
- Ultra-small footprint
  - 1.53 mm × 0.77 mm
- Low profile
  - 0.36-mm height
- Integrated ESD protection diode
- Lead and halogen free
- RoHS compliant

2 Applications

- Optimized for industrial load switch applications
- Optimized for general purpose switching applications

3 Description

This 54-mΩ, 60-V, N-Channel FemtoFET™ MOSFET technology is designed and optimized to minimize the footprint in many space constrained industrial load switch applications. This technology is capable of replacing standard small signal MOSFETs while providing a significant reduction in footprint size.



Typical Part Dimensions

Product Summary

T_A = 25°C		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	60		V
Q_g	Gate Charge Total (10 V)	11		nC
Q_{gd}	Gate Charge Gate-to-Drain	1.6		nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	V_{GS} = 4.5 V	57	mΩ
		V_{GS} = 10 V	54	
$V_{GS(th)}$	Threshold Voltage	1.75		V

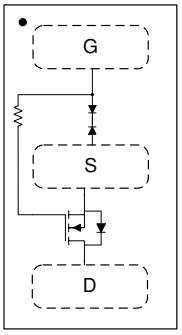
Device Information

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD18541F5	3000	7-Inch Reel	Femto 1.53-mm × 0.77-mm SMD Lead Less	Tape and Reel
CSD18541F5T	250			

1. For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T_A = 25°C		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	60	V
V_{GS}	Gate-to-Source Voltage	±20	V
I_D	Continuous Drain Current	2.2	A
I_{DM}	Pulsed Drain Current (1)(2)	21	A
P_D	Power Dissipation	500	mW
T_J, T_{stg}	Operating Junction Temperature, Storage Temperature	–55 to 150	°C
E_{AS}	Avalanche Energy, Single Pulse I_D = 12.8 A, L = 0.1 mH, R_G = 25 Ω	8.2	mJ



Top View

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (December 2016) to Revision B (February 2022)	Page
• Changed ultra-low profile bullet from 0.35 mm to 0.36 mm in height	1
• Updated ultra-low profile image height from 0.35 mm to 0.36 mm	1
• Changed ultra-low profile image height from 0.35 mm to 0.36 mm	8
• Added FemtoFET Surface Mount Guide note	9

Changes from Revision * (May 2016) to Revision A (August 2017)	Page
• Added the *Section 6.1* section to *Section 6*	7
• Added *Table 7-1* to the *Section 7.1* section	8
• Updated the *Section 7.2*	9
• Updated the *Section 7.3*	9

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5 Specifications

5.1 Electrical Characteristics

T_A = 25°C (unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV_{DSS}	Drain-to-source voltage	V_{GS} = 0 V, I_{DS} = 250 µA	60			V
I_{DSS}	Drain-to-source leakage current	V_{GS} = 0 V, V_{DS} = 48 V			1	µA
I_{GSS}	Gate-to-source leakage current	V_{DS} = 0 V, V_{GS} = 20 V			10	µA
$V_{GS(th)}$	Gate-to-source threshold voltage	V_{DS} = V_{GS}, I_{DS} = 250 µA	1.4	1.75	2.2	V
$R_{DS(on)}$	Drain-to-source on-resistance	V_{GS} = 4.5 V, I_{DS} = 1 A		57	75	mΩ
		V_{GS} = 10 V, I_{DS} = 1 A		54	65	
g_{fs}	Transconductance	V_{DS} = 6 V, I_{DS} = 1 A		7.7		S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input capacitance	V_{GS} = 0 V, V_{DS} = 30 V, f = 1 MHz		598	777	pF
C_{oss}	Output capacitance			47	61	pF
C_{rss}	Reverse transfer capacitance			8.1	10.5	pF
R_G	Series gate resistance			1200	1600	Ω
Q_g	Gate charge total (10 V)	V_{DS} = 30 V, I_{DS} = 1 A		11	14	nC
Q_{gd}	Gate charge gate-to-drain			1.6		nC
Q_{gs}	Gate charge gate-to-source			1.5		nC
$Q_{g(th)}$	Gate charge at V_{th}			0.8		nC
Q_{oss}	Output charge	V_{DS} = 30 V, V_{GS} = 0 V		3.2		nC
$t_{d(on)}$	Turnon delay time	V_{DS} = 30 V, V_{GS} = 4.5 V, I_{DS} = 1 A, R_G = 0 Ω		572		ns
t_r	Rise time			540		ns
$t_{d(off)}$	Turnoff delay time			1076		ns
t_f	Fall time			496		ns
DIODE CHARACTERISTICS						
V_{SD}	Diode forward voltage	I_{SD} = 1 A, V_{GS} = 0 V		0.8	1	V

5.2 Thermal Information

T_A = 25°C (unless otherwise stated)

THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance(1)		85		°C/W
	Junction-to-ambient thermal resistance(2)		245		

(1) Device mounted on FR4 material with 1-in^2 (6.45-cm^2), 2-oz (0.071-mm) thick Cu.
(2) Device mounted on FR4 material with minimum Cu mounting area.

5.3 Typical MOSFET Characteristics

T_A = 25°C (unless otherwise stated)

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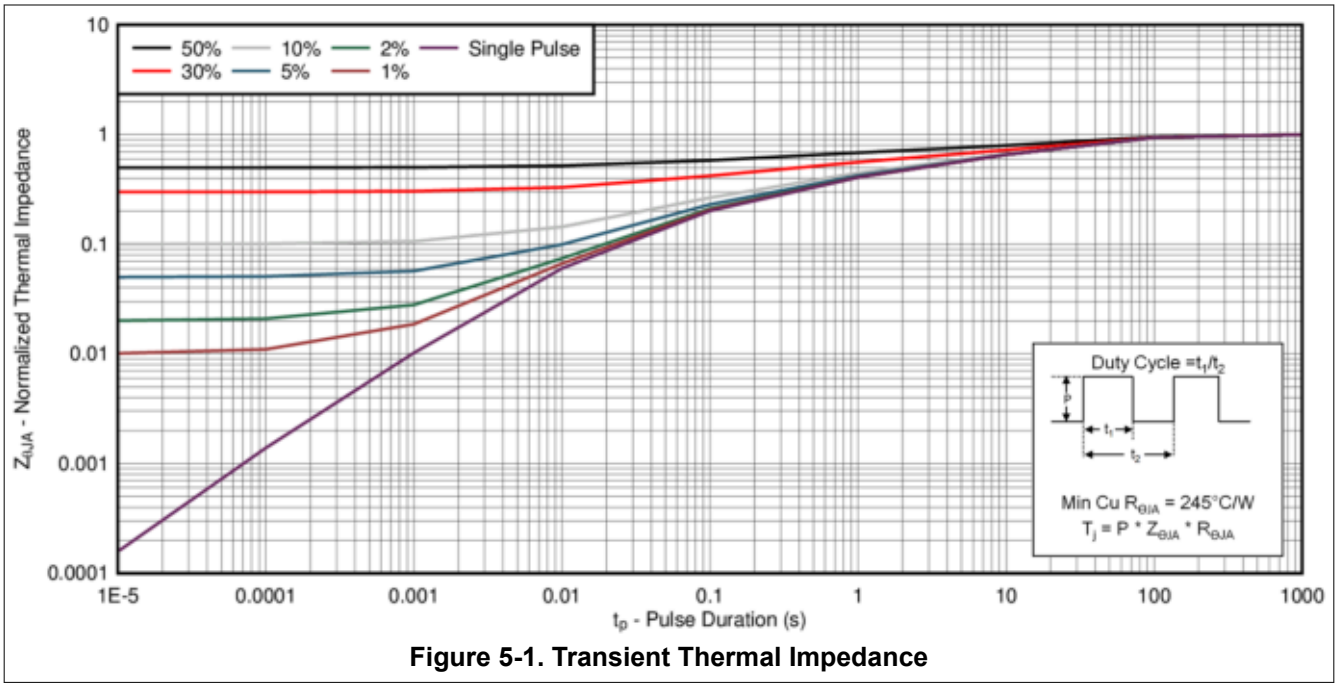


Figure 5-1. Transient Thermal Impedance

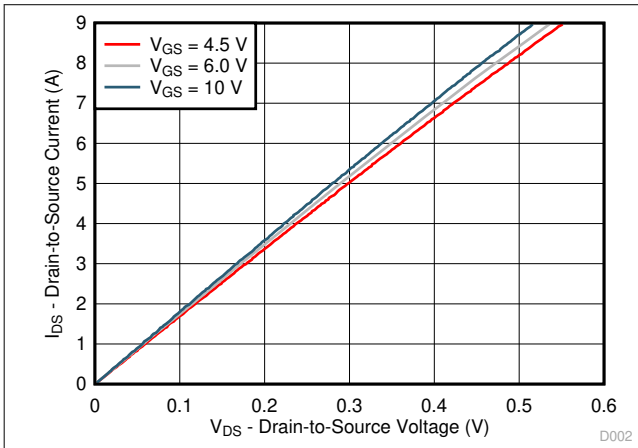
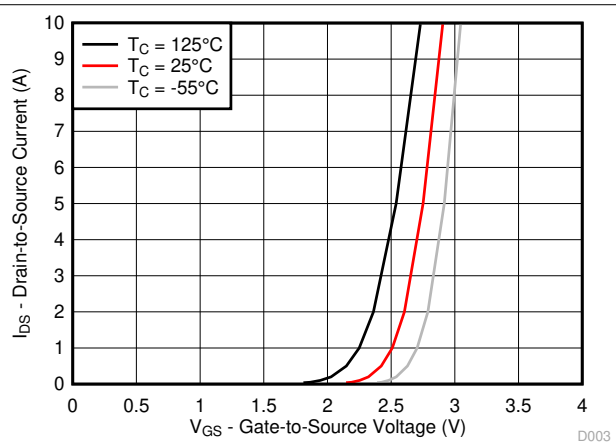


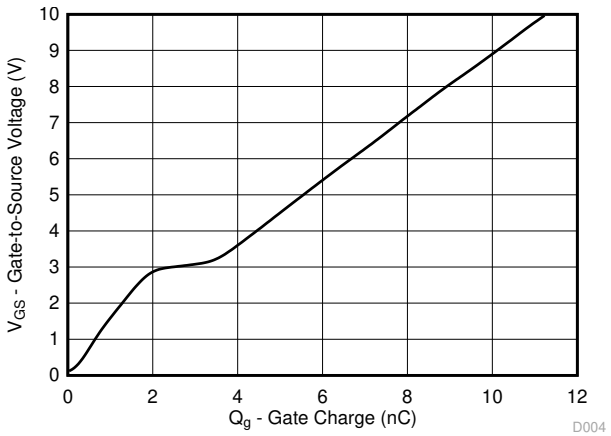
Figure 5-2. Saturation Characteristics



VDS = 5 V

Figure 5-3. Transfer Characteristics

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I_D = 1 A V_{DS} = 30 V

Figure 5-4. Gate Charge

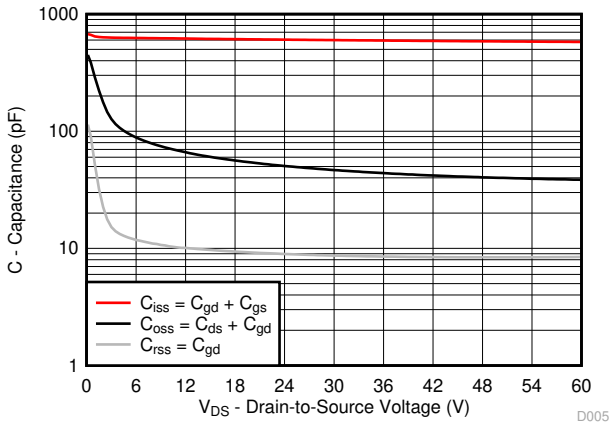
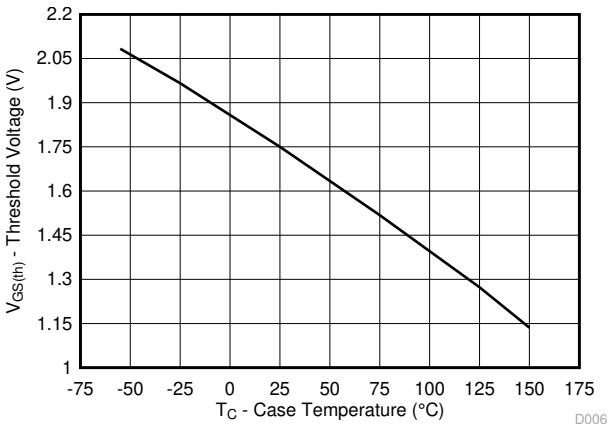


Figure 5-5. Capacitance



I_D = 250 µA

Figure 5-6. Threshold Voltage vs Temperature

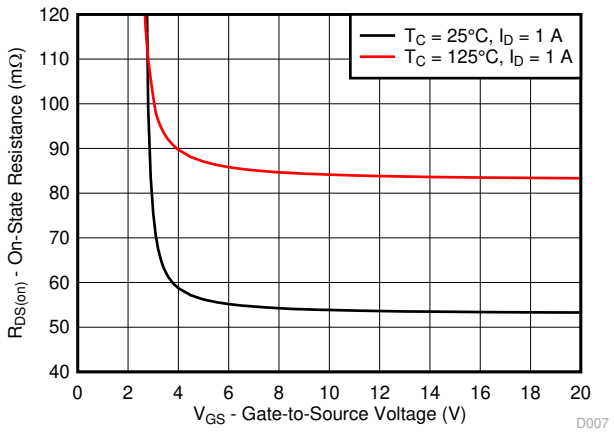
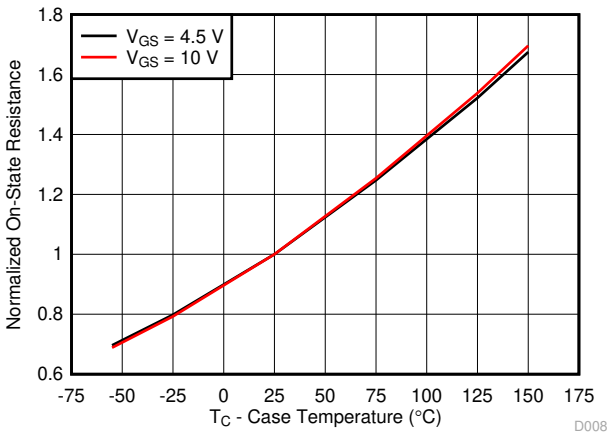


Figure 5-7. On-State Resistance vs Gate-to-Source Voltage



I_D = 1 A

Figure 5-8. Normalized On-State Resistance vs Temperature

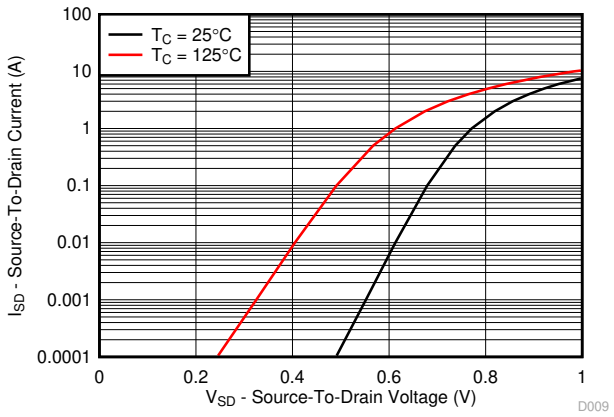
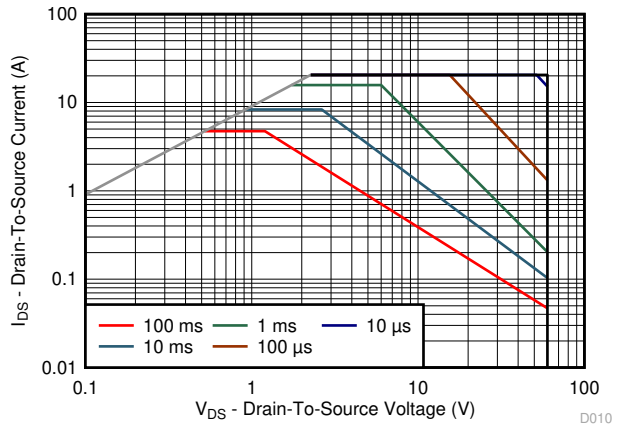


Figure 5-9. Typical Diode Forward Voltage

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Single pulse, typ $R_{\theta JA}$ = 245°C/W

Figure 5-10. Maximum Safe Operating Area (SOA)

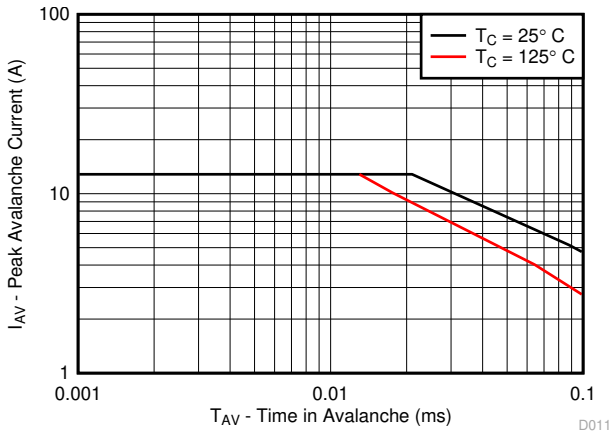


Figure 5-11. Single Pulse Unclamped Inductive Switching

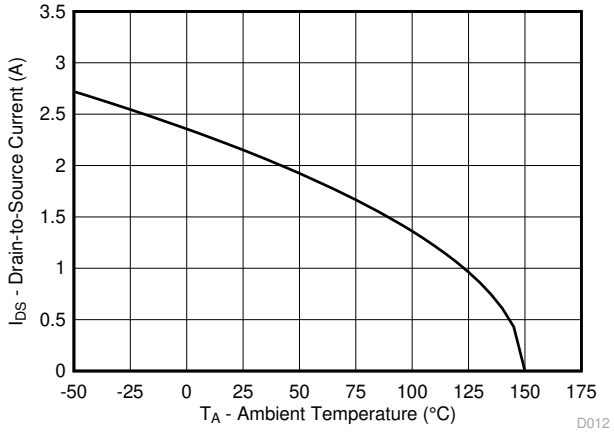


Figure 5-12. Maximum Drain Current vs Temperature

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6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

6.3 Trademarks

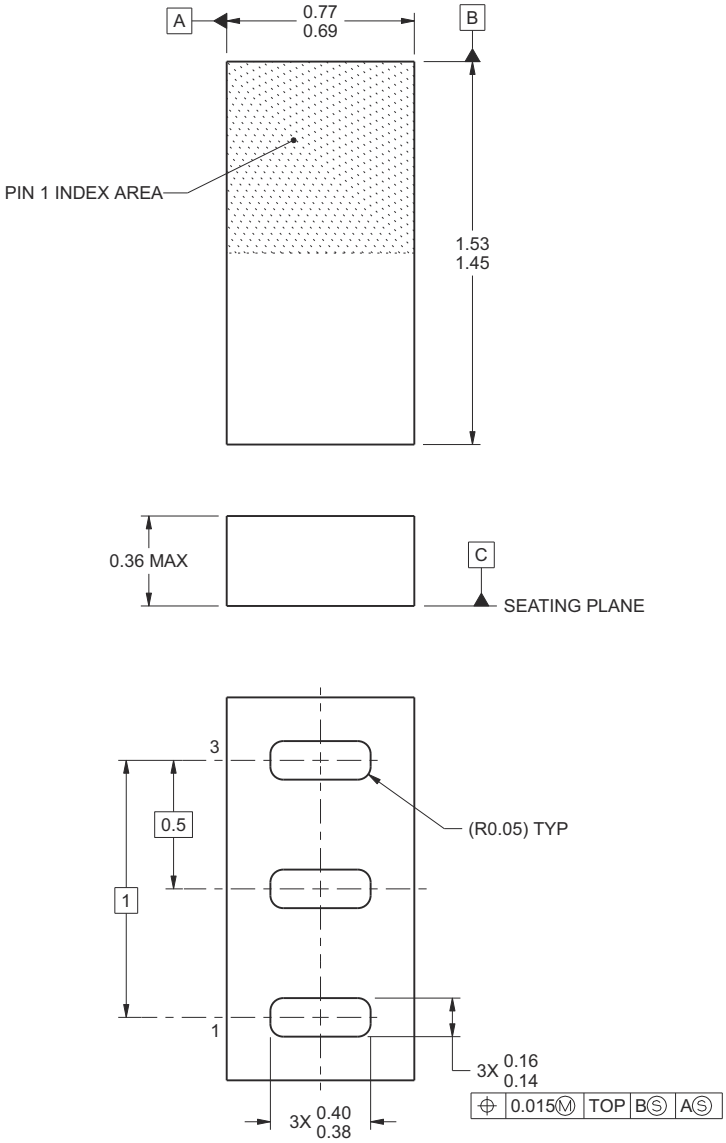
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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Mechanical Dimensions



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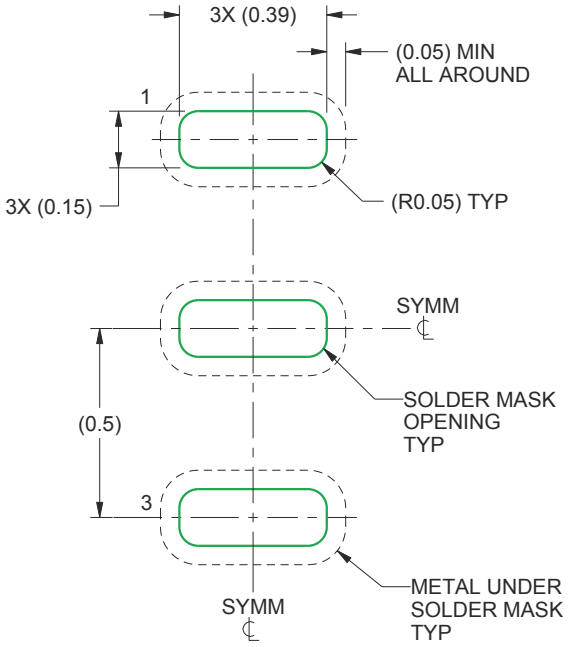
A. All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994).
B. This drawing is subject to change without notice.
C. This package is a PB-free solder land design.

Table 7-1. Pin Configuration

POSITION	DESIGNATION
Pin 1	Gate
Pin 2	Source
Pin 3	Drain

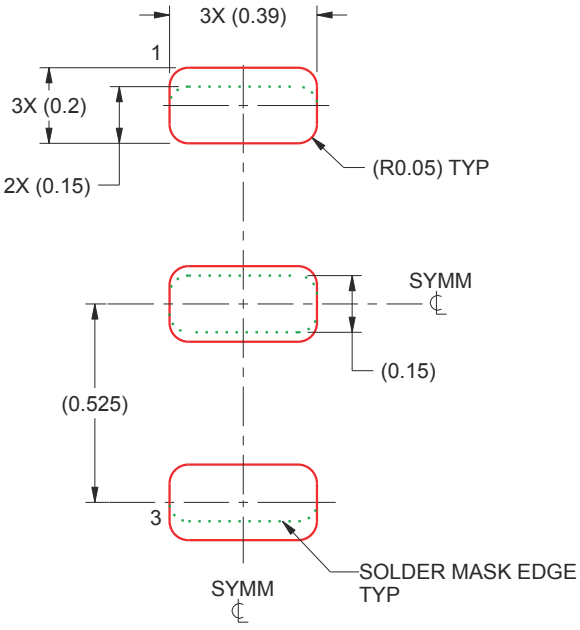
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7.2 Recommended Minimum PCB Layout



A. All dimensions are in millimeters.
B. For more information, see *FemtoFET Surface Mount Guide* (SLRA003D).

7.3 Recommended Stencil Pattern



A. All dimensions are in millimeters.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD18541F5	Active	Production	PICOSTAR (YJK) | 3	3000 | LARGE T&R	Yes	NIPD	Level-1-260C-UNLIM	-55 to 150	1T
CSD18541F5.B	Active	Production	PICOSTAR (YJK) | 3	3000 | LARGE T&R	Yes	NIPD	Level-1-260C-UNLIM	-55 to 150	1T
CSD18541F5T	Active	Production	PICOSTAR (YJK) | 3	250 | SMALL T&R	Yes	NIPD	Level-1-260C-UNLIM	-55 to 150	1T
CSD18541F5T.B	Active	Production	PICOSTAR (YJK) | 3	250 | SMALL T&R	Yes	NIPD	Level-1-260C-UNLIM	-55 to 150	1T

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

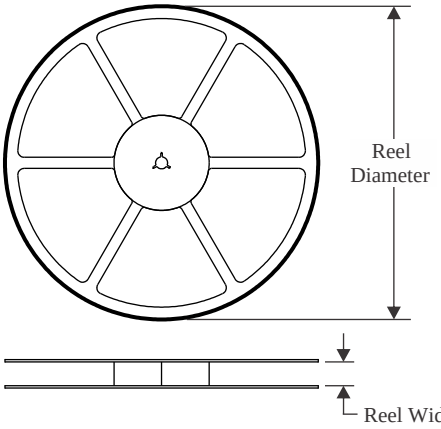
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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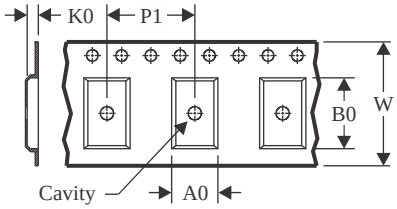
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

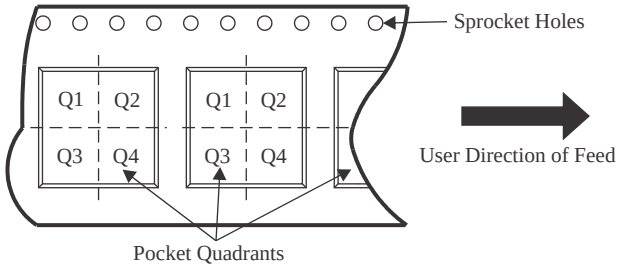


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

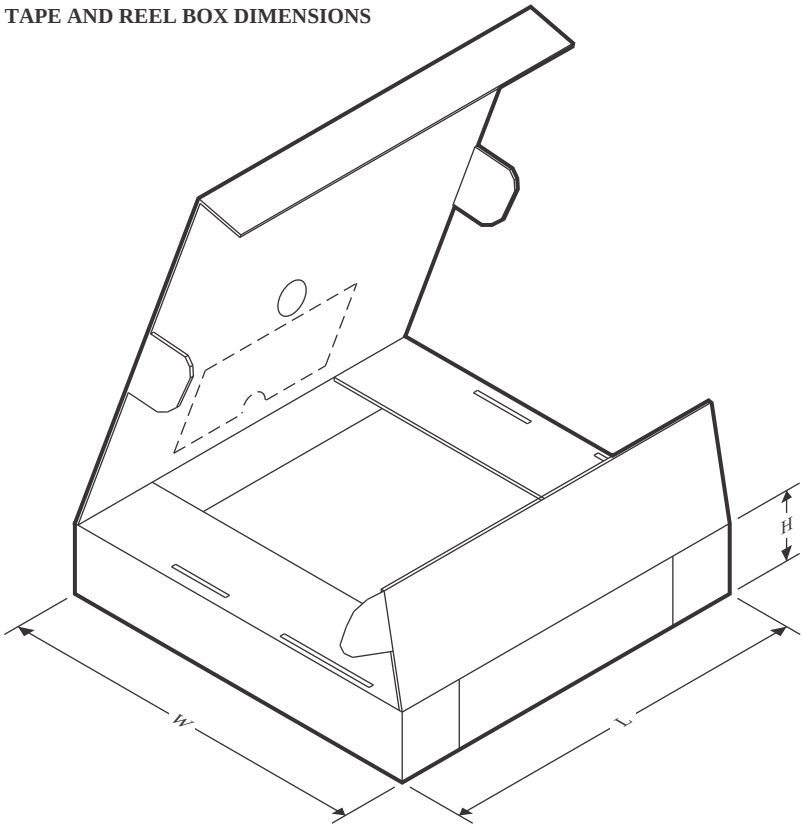
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD18541F5	PICOSTAR	YJK	3	3000	180.0	8.4	0.92	1.68	0.42	4.0	8.0	Q1
CSD18541F5T	PICOSTAR	YJK	3	250	180.0	8.4	0.92	1.68	0.42	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

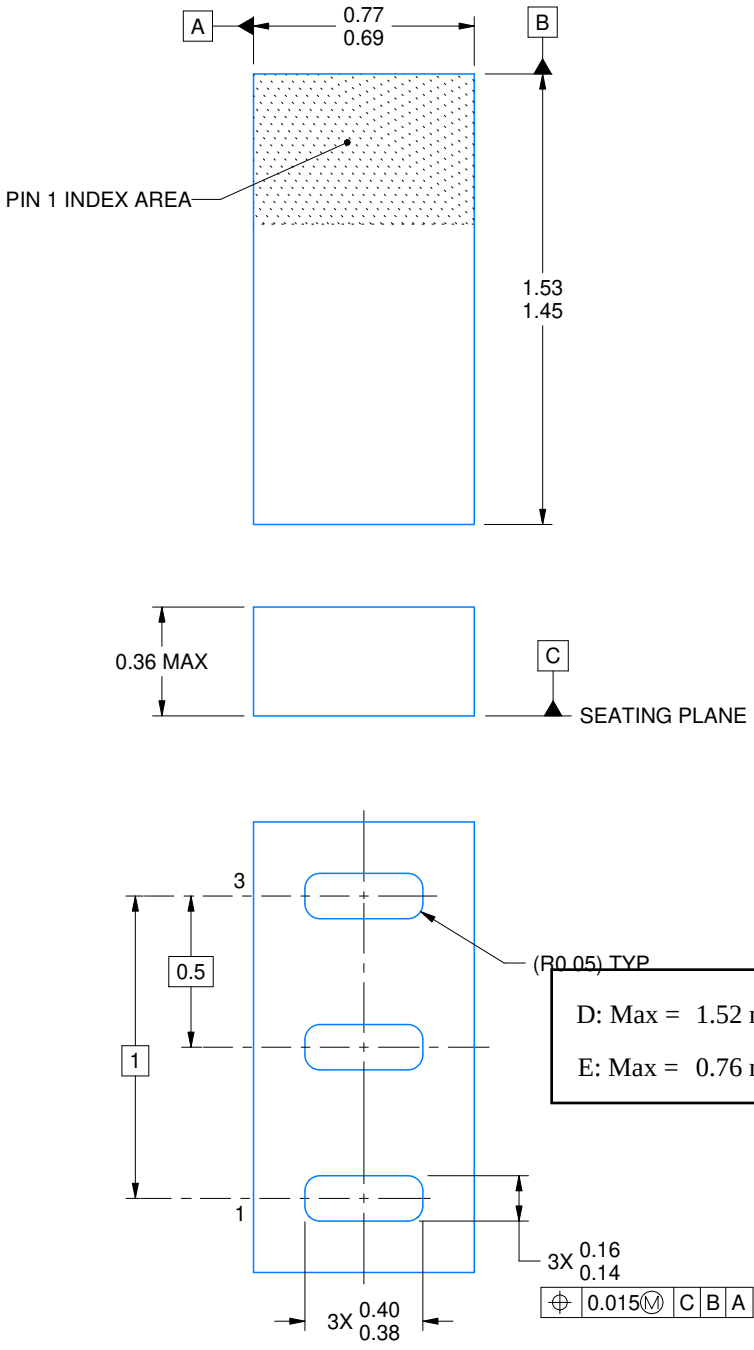
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD18541F5	PICOSTAR	YJK	3	3000	182.0	182.0	20.0
CSD18541F5T	PICOSTAR	YJK	3	250	182.0	182.0	20.0

PACKAGE OUTLINE

YJK0003A

PicoStar™ - 0.36 mm max height

PicoStar™

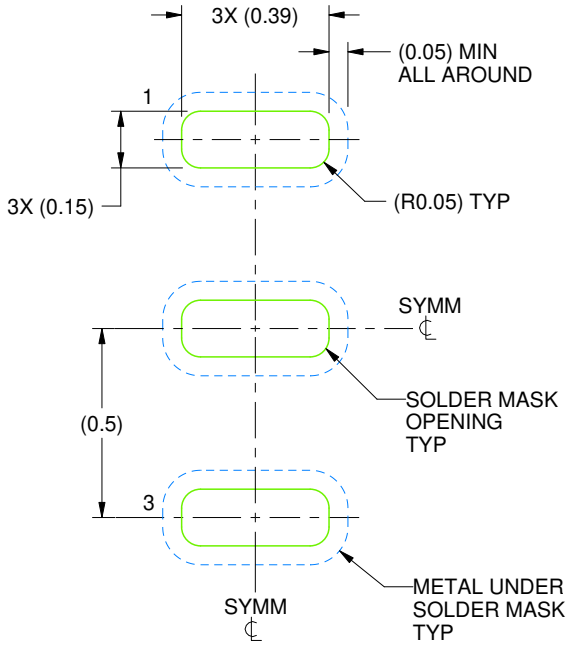


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PicoStar is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M
2. This drawing is subject to change without notice.
3. This package is a Pb-free bump design. Bump finish may vary. To determine the exact finish, refer to the device datasheet or contact a local TI representative.

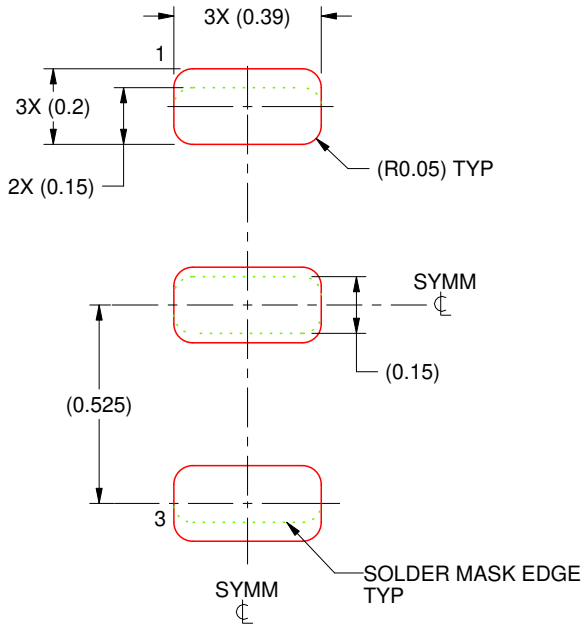


LAND PATTERN EXAMPLE
SOLDER MASK DEFINED
SCALE:50X

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NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:50X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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